

**High-performance Clock Generator Series** 

# **Clock Generators** with built-in VCXO for A/V Equipment



# **BU2365FV**

# Description

The ROHM Clock Generator is an IC allowing for the generation of multiple clocks by a single chip through the connection of a single crystal oscillator. The BU2365FV incorporates the ROHM's unique PLL technology to provide the generation of multiple high C/N clocks necessary for the DVD recorder system. This Clock Generator has the built-in high-precision VCXO function and allows for high-precision synchronization with DVD Video clocks. It also has a built-in buffer having high driving force and allows the supply of multiple 27MHz Video clocks for the system, thus providing the reduced number of the system components.

#### Features

- 1) The unique PLL technology allows for the generation of high C/N clocks.
- 2) Built-in high precision VCXO, which is essential for the DVD recorder system
- 3) Built-in buffer having high driving force (Load capacity/output CL=50pF, 27MHz drive, 1×input / 2×outputs)
- 4) Built-in half pulse clock protection [HPC]
- 5) Built-in power down function, Icc=0 uA(typ.)
- 6) SSOP-B24 package
- 7) Single power supply of 3.3 V

# Applications

DVD recorder

# ■Absolute maximum ratings (Ta=25°C)

Absolute maximum ratings (1a-25 C)				
Parameter	Symbol	Limit	Unit	
Supply voltage	VDD	-0.3~7.0	V	
Input voltage	VIN	−0.3~VDD+0.3	V	
Storage temperature range	Tstg	-30~125	င	
Power dissipation	PD	820	mW	

<sup>\*1</sup> Operation is not guaranteed.

Ver.B Oct.2005

<sup>\*2</sup> Reduce by 8.2mW/°C over 25°C

<sup>\*3</sup> This IC is not designed to be radiation-resistant.

<sup>\*4</sup> Power dissipation is measured when the IC is mounted to the printed circuit board.

Recommended operating range

Parameter	Symbol	Limit	Unit
Supply voltage	VDD	3.0~3.6	V
Input H voltage	VINH	0.8VDD~VDD	V
Input L voltage	VINL	0.0~0.2VDD	V
Operating temperature	Topr	<b>−10~70</b>	°C
Output load			
22Pin / 19Pin	CL_CLK768FS/384FS	32(max.)	pF
13Pin , 14Pin	CL_BUFOUT	50(max.)	pF
18Pin / 24Pin	CL_CLK512FS/54M	15(max.)	pF

# Electrical characteristics

VDD=3.3V, Ta=25°C, Crystal frequency (XTAL\_IN)=27.000000MHz, at no load, unless otherwise specified.

December .	Limit		Linit	O and this n		
Parameter	Symbol	Min.	Тур.	Max.	- Unit	Condition
[Consumption circuit current]	IDD	-	55	71.5	mA	At no output loads
[Output H voltage]	VOH	2.4	_	_	V	When current load = -4.0mA
【Output L voltage】	VOL	_	_	0.4	V	When current load =4.0mA
【Pull-Up resistance value】 FSEL、OE	Pull-Up R	168	260	578	kΩ	Specified by a current value running when a voltage of 0V is applied to a measuring pin. (R=VDD/I)
【Pull-Down resistance value】 TEST	Pull-down R	31	48	106	kΩ	Specified by a current value running when a VDD is applied to a measuring pin. (R=VDD/I)
[Output frequency]						
CLK768FS : FSEL=L	CLK768 FS_L		33.868800		MHz	XTAL_IN×(3136/625)/4
CLK768FS : FSEL=H	CLK768 FS_H		36.864000		MHz	XTAL_IN×(2048/375)/4
CLK384FS	CLK384 FS		18.432000		MHz	XTAL_IN×(2048/375)/8
CLK512FS	CLK512 FS		24.576000		MHz	XTAL_IN×(2048/375)/6
CLK54M	CLK54M		54.000000		MHz	XTAL_IN×(32/4)/4
[Output waveform]						
Duty	Duty1	45	50	55	%	Measured at a voltage of 1/2 of VDD
Rise time	Tr		2.5		nsec	Period of time required for the output to reach 80% from 20% of VDD
Fall time	Tf		2.5		nsec	Period of time required for the output to reach 20% from 80% of VDD
[Jitter]						
Period-Jitter 1σ	P-J1σ		50		psec	<b>%1</b>
Period-Jitter MIN-MAX	P-J MIN-MAX		300		psec	<b>*2</b>
[Output Lock-Time]	Tlock			1	msec	<b>%</b> 3
[Frequency stability]	ΔF/F0	<b>-15</b>		15	ppm	T=-10~70℃、VDD=3.3V± 0.15V ※4
[Frequency sensitivity]	ΔF/Fc	±30	±45	±60	ppm	<b>%</b> 5
[Frequency sensitivity linearity]	Linearity	-10		10	ppm	<b>%</b> 5
[Buffer skew]	Tskew _BUF	-500		500	psec	Phase difference between BUF_OUT1 and BUF_OUT2*6
[Buffer delay]	Td_BUF		4	8	nsec	Phase difference between BUF_IN and BUF_OUT

Note: The output frequency is determined by the arithmetic (frequency division) expression of a frequency input to XTAL\_IN.

#### %1 Period-Jitter 1σ

This parameter represents standard deviation (=1σ) on cycle distribution data when the output clock cycles are sampled 1000 times consecutively, with the TDS7104 Digital Phosphor Oscilloscope of Tektronix Japan, Ltd.

#### %2 Period-Jitter MIN-MAX

This parameter represents a maximum distribution width on cycle distribution data when the output clock cycles are sampled 1000 times consecutively, with the TDS7104 Digital Phosphor Oscilloscope of Tektronix Japan, Ltd.

### **%3 Output Lock-Time**

This parameter represents the elapsed time to reach a voltage of 3.0V after power supply turns ON and after the system is switched from power-down to normal operation state, or after the output frequency is switched and is stabilized.

#### **%4** Frequency stability

f0 : This parameter means an optimum frequency at T=25°C(27.000000 MHz). Frequency is dependent on the stability of the crystal oscillator. Precautions should be taken when designing the system.

#### %5 Frequency sensitivity/Frequency sensitivity linearity

This parameter represents the frequency that falls within the area shown in Fig. 2, in the control circuit of control voltage shown in Fig. 1. It shows the value of the IC. Since no consideration is given to the stability of the crystal oscillator, it should be separately studied according to the system in use.

### Common – Recommended crystal oscillators

The electrical characteristics shown above have been all evaluated with the use of the crystal oscillator NX5032GA (Spec. No. EXS00A-00278) manufactured by NIHON DEMPA KOGYO CO., LTD., under the conditions of Limiting resistance Rd= $30\Omega$  and Crystal oscillator load CL=10pF. Consequently, in order to use the BU2365FV, the specified crystal oscillator is recommended.

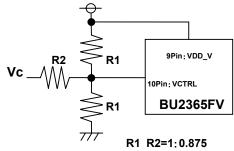
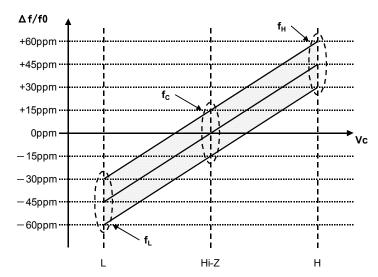


Fig.1 Control Circuit of Control Voltage



Frequency sensitivity dispersion range:  $f_L$ =  $-45\pm15$ ppm,  $f_C$ =  $0\pm15$ ppm,  $f_H$ =  $45\pm15$ ppm However, frequency sensitivity linearity: -10ppm $\leq$ ( $f_H$  -  $f_C$ ) -( $f_C$  -  $f_L$ )  $\leq$  +10ppm Fig. 2 Frequency Sensitivity Dispersion Range

# %6 Buffer skew

This parameter is only functional when the BUF\_OUT1 and the BUF\_OUT2 are driven at the same load capacitance

# ● Reference data (Basic data)

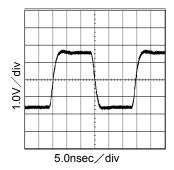


Fig.3 33.8688MHz output waveform VDD=3.3V,CL=32pF

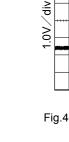


Fig.4 33.8688MHz Period-Jitter VDD=3.3V,CL=32pF

500psec/div

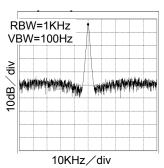


Fig.5 33.8688MHz spectrum VDD=3.3V,CL=32pF

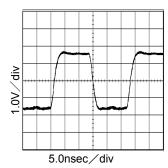


Fig.6 36.864MHz output waveform VDD=3.3V,CL=32pF

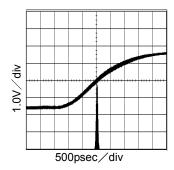


Fig.7 36.864MHz Period-Jitter VDD=3.3V,CL=32pF

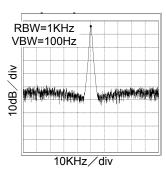


Fig.8 36.864MHz spectrum VDD=3.3V,CL=32pF

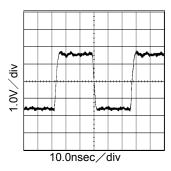


Fig.9 18.432MHz output waveform VDD=3.3V,CL=32pF

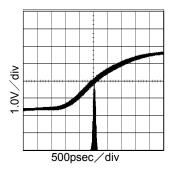


Fig.10 18.432MHz Period-Jitter VDD=3.3V,CL=32pF

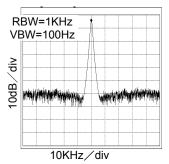


Fig.11 18.432MHz spectrum VDD=3.3V,CL=32pF

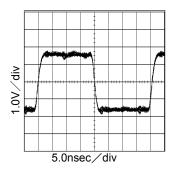


Fig.12 24.576MHz output waveform VDD=3.3V,CL=15pF

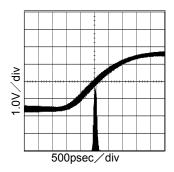


Fig.13 24.576MHz Period-Jitter VDD=3.3V,CL=15pF

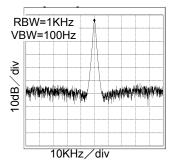


Fig.14 24.576MHz spectrum VDD=3.3V,CL=15pF

### ● Reference data (Basic data)

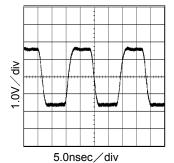
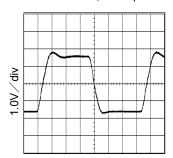


Fig.15 54MHz output waveform VDD=3.3V,CL=15pF



5.0nsec / div
Fig.18 BUF\_OUT(27MHz) output
waveform
VDD=3.3V,CL=50pF

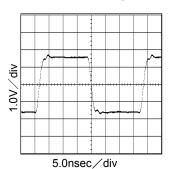


Fig.21 VCXO\_OUT(27MHz) output waveform VDD=3.3V,CL=4pF

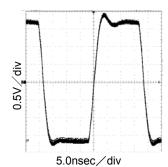


Fig.24 Buffer skew output waveform VDD=3.3V,CL=50pF

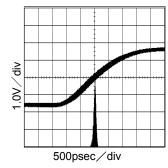


Fig.16 54MHz Period-Jitter VDD=3.3V,CL=15pF

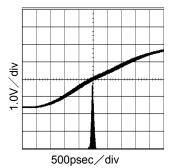


Fig.19 BUF\_OUT(27MHz) Period-Jitter VDD=3.3V,CL=50pF

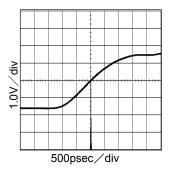


Fig.22 VCXO\_OUT(27MHz) Period-Jitter VDD=3.3V,CL=4pF

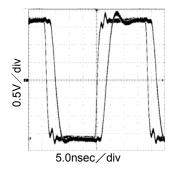


Fig.25 Buffer delay(IN→OUT1) VDD=3.3V,CL=50pF

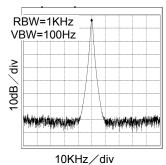


Fig.17 54MHz spectrum VDD=3.3V,CL=15pF

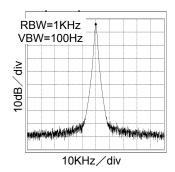


Fig.20 BUF\_OUT(27MHz) spectrum VDD=3.3V,CL=50pF

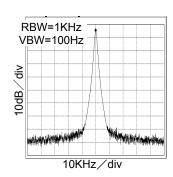


Fig.23 VCXO\_OUT(27MHz) spectrum VDD=3.3V,CL=4pF

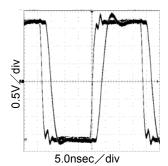
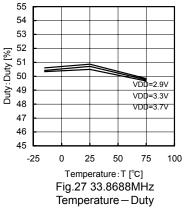
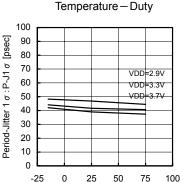


Fig.26 Buffer delay(IN→OUT2) VDD=3.3V,CL=50pF

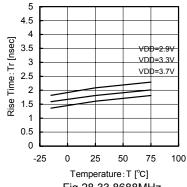
# ● Reference data (PLL: 33.8688MHz output - Temperature and Supply voltage variations data)





Temperature:T [°C]

Fig.30 33.8688MHz Temperature – Period-Jitter 1σ



4.5

3.5

2.5

Fall Time :Tf[nsec]

4

3

2

1.5

1

0

-25

0 25

0.5

VDD=2.9\

VDD=3.3V

VDD=3.7V

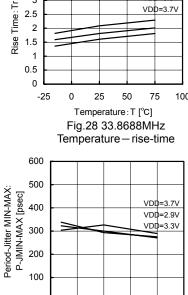
75 100

50

Temperature: T [°C]

Fig.29 33.8688MHz

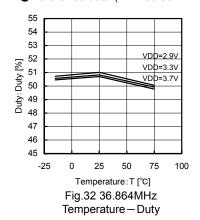
Temperature - fall-time

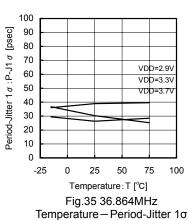


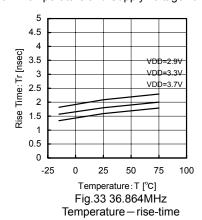
0 25 50 -25 75 Temperature:T [°C] Fig.31 33.8688MHz

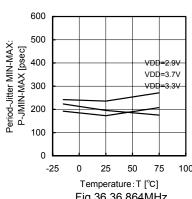
Temperature - Period-Jitter MIN-MAX

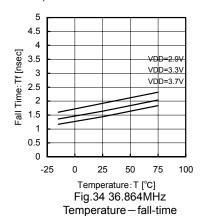
#### ●Reference data (PLL: 36.864MHz output Temperature and Supply voltage variations data)





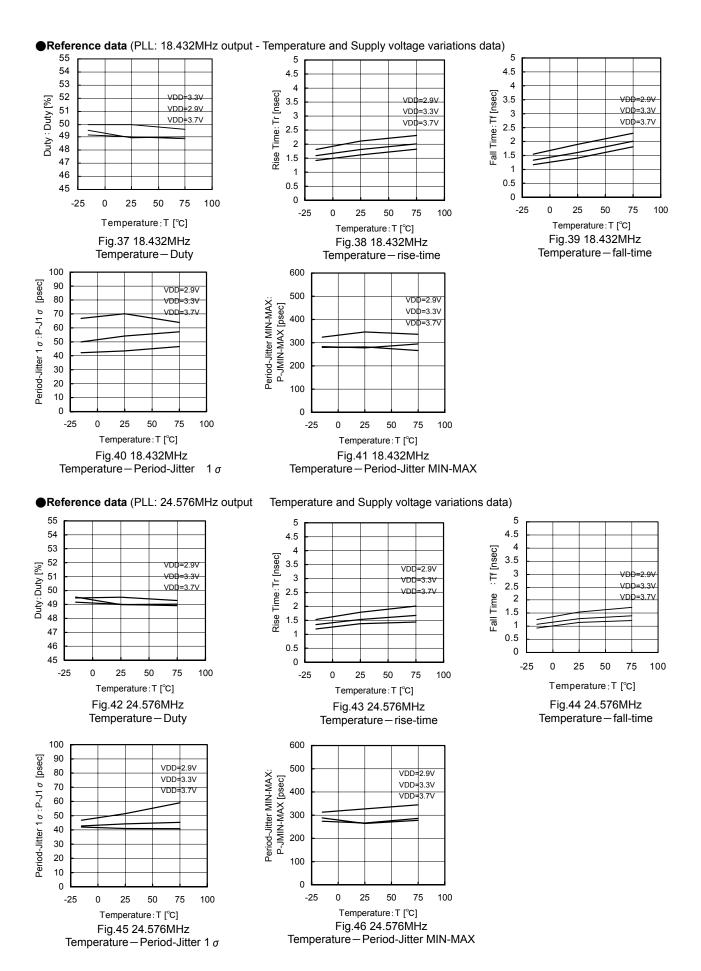




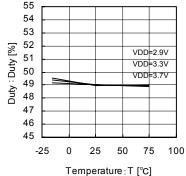


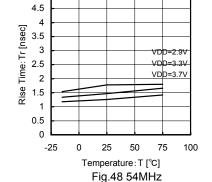
100 Fig.36 36.864MHz

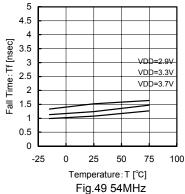
Temperature - Period-Jitter MIN-MAX





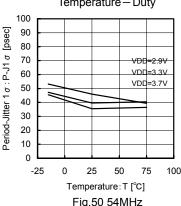






Temperature - fall-time

Fig.47 54MHz Temperature - Duty



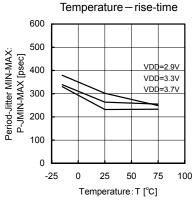


Fig.51 54MHz Temperature - Period-Jitter MIN-MAX

VDD=2.9V

VDD=3.3V

VDD=3.7V

75 100

# ● Reference data (CLOCK-BUFFER: 27MHz output

VDD=2.9V

VDD=3.3V

VDD=3.7V

Temperature – Period-Jitter 1σ

54

53

52

50

49

48

47

46

45

8

5

4

3

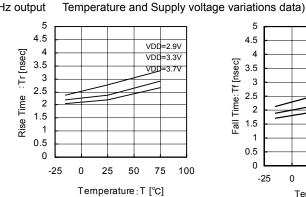
2

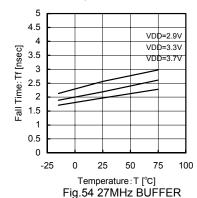
O

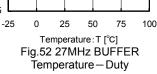
-25

Buffer Delay: Td BUF [nsec]

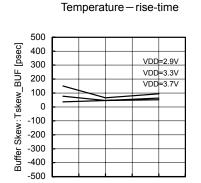
Duty: Duty [%] 51





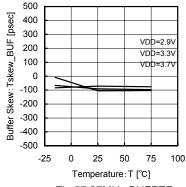






25

Fig.53 27MHz BUFFER



Temperature – fall-time

Temperature:T [°C] Fig.55 27MHz BUFFER Temperature - Delay

50

75

25

Temperature:T [°C] Fig.56 27MHz BUFFER Temperature - Skew (BUF\_OUT2 Phase Lead)

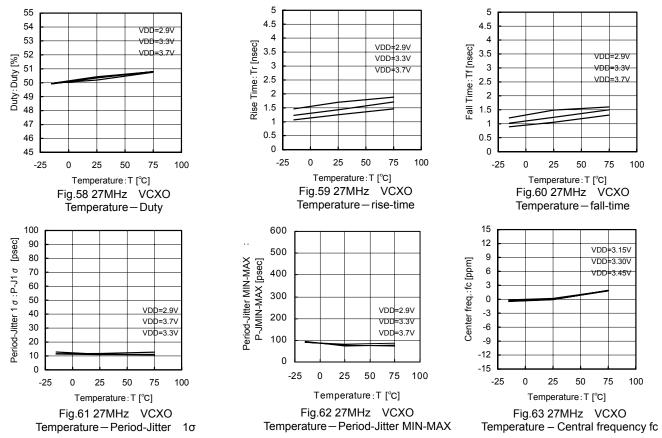
50 75 100

Fig.57 27MHz BUFFER Temperature - Skew (BUF\_OUT2 Phase Delay)

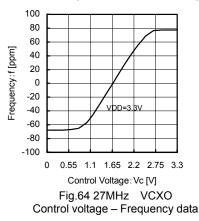
0

-25

●Reference data (VCXO:27MHz output - Temperature and Supply voltage variations data)
This data represents the central frequency as a deviation to the optimum frequency of 27.000000MHz.



Reference data (VCXO: 27MHz output Control voltage – Frequency data)
This data represents the central frequency as a deviation to the optimum frequency of 27.000000MHz.



Reference data (BU2365FV consumption current 5 Temperature and Supply voltage variations data) 100 4.5 Standby Current : Iccs [µA] 95 4 90 Circuit Current: Icc [mA] 3.5 VDD=3.7V 85 3 VDD±3.3V 80 2.5 <u>VDD</u>=2.9V 75 2 70 1.5 VDD=3.7V 65 1 VD\$=3.3V 60 0.5 VDD=2.9V 55 0 50 -25 0 25 50 75 100 -25 0 25 50 75 Temperature: T [°C] Temperature:T [°C] Fig.66 Power-down Fig.65 Maximum Load

**Standby Current** 

9/16

Operating Circuit Current

### ● Reference data (PLL : Long Term Jitter data)

This data represents Period-Jitter at the 1000th cycle.

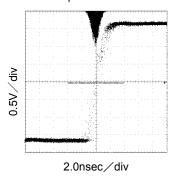


Fig.67 33.8688MHz Long Term Jitter

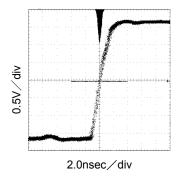


Fig.68 36.864MHz Long Term Jitter

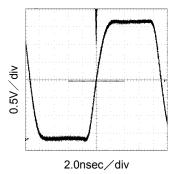
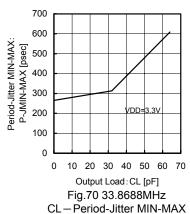


Fig.69 54MHz Long Term Jitter

# ● Reference data (Period-Jitter MIN-MAX Output load CL dependence data)

This data represents the output load up to two times as high as the maximum load of each output.

Since the 27-MHz buffer is dependent on the jitter of a clock input, the output is represented by the ratio to the jitter at 50pF.



700 600 600 200 500 XYW1 300 100 0 5 10 15 20 25 30

Output Load: CL [pF]

Period-Jitter MIN-MAX:

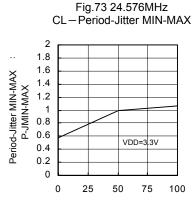
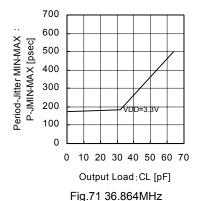
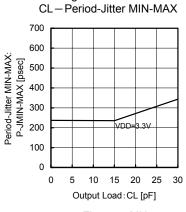


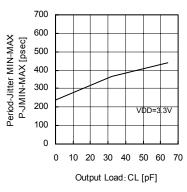
Fig.76 27MHz BUFFER CL—Period-Jitter MIN-MAX

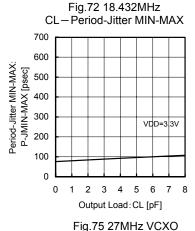
Output Load: CL [pF]











CL-Period-Jitter MIN-MAX

# ●Block diagram, Pin assignment

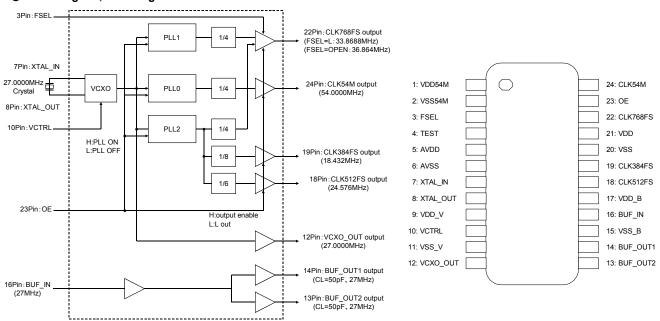


Fig.77 Block diagram

Fig.78 Pin assignment

# Pin function

Fill fullet	OII	,			
Pin No.	Pin Name	Function			
1	VDD54M	Power supply for CLK54M output			
2	VSS54M	GND for CLK54M output			
3	FSEL	FS select (CLK768FS selection)			
		(FSEL=L: 44.1 kHz, FSEL=OPEN: 48 kHz, equipped with pull-up resistor)			
4	TEST	TEST pin, normally "OPEN", equipped with pull-down resistor)			
5	AVDD	Power supply for PLL Analog			
6	AVSS	GND for PLL Analog			
7	XTAL_IN	Crystal oscillator input pin			
8	XTAL_OUT	Crystal oscillator output pin			
9	VDD_V	Power supply for VCXO			
10	VCTRL	VCXO control input pin			
11	VSS_V	GND for VCXO			
12	VCXO_OUT	Monitor pin for VCXO output			
13	BUF_OUT2	BUFFER output pin			
14	BUF_OUT1	BUFFER output pin			
15	VSS_B	GND for BUFFER			
16	BUF_IN	BUFFER input pin			
17	VDD_B	Power supply for BUFFER			
18	CLK512FS	24.576 MHz output			
19	CLK384FS	18.432MHz output			
20	VSS	GND for PLL Logic			
21	VDD	Power supply for PLL Logic			
22	CLK768FS	FSEL=L: 33.8688 MHz output, FSEL=OPEN: 36.864 MHz output			
23	OE	Output enable pin			
		L: POWER DOWN, OPEN: NORMAL, equipped with pull-up resistor			
24	CLK54M	54MHz output			

#### Audio clock functions

#### 1) Output phase relation

The Audio clocks (CLK768FS, CLK384FS, and CLK512FS) of the BU2365FV are designed to be out of the phase from each output in order to provide low jitter and noise levels.

Generating CLK384FS (18.432 MHz): A two-phase clock is generated for CLK768FS (36.864 MHz): The CLK768FS1 and CLK768FS2 with the phase relation to the PLL2 output (VCO=147.456 MHz) (See Fig. 79). By dividing the frequency in sync with the leading edge of this CLK768FS1, the CLK384FS will fall out of the phase of the CLK768FS2.

Since the frequency of CLK512FS is divided into six portions in sync with the trailing edge of the PLL2 output, the CLK512FS will fall out of the phases of CLK768FS and CLK384FS by half cycle.

Furthermore, the true values of phase difference (Delay rate) between CLK384FS and CLK768FS are specified as shown below with consideration given to variations in the measurements on the tests before shipment.

	MIN	TYP	MAX
True value [nsec]	17.0	20.0	23.0

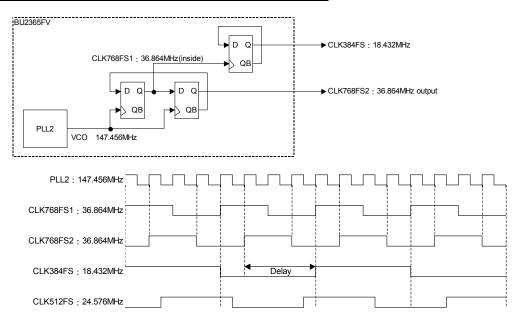


Fig. 79 Audio Clock Output Circuit Configuration and Timing Chart

# 2) Half-pulse clock protection [HPC]

The CLK768FS output is provided with a function used to prevent the a half cycle (or less) synchronous drop (i.e., half-pulse clock) during frequency selection under the control of the FSEL pin.

This function is designed to set the frequency to output L fixed after the elapse of two trailing clocks of output before the selection and to a desired frequency after the elapse of two trailing clocks of output after the selection, when switching the FSEL pin.

Specifically speaking, when the FSEL pin is set to High, the CLK768FS outputs a frequency of 36.864 MHz. With this setting, if the FSEL pin is switched to Low, the CLK768FS will be set to L Fixed after the lapse of two trailing clocks of 36.864 MHz, and then the CLK768FS will output a frequency of 33.8688 MHz after the lapse of two trailing clocks of 33.8688 MHz.

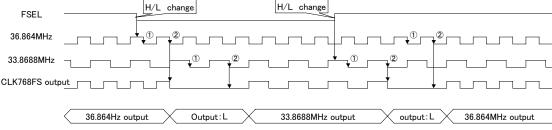


Fig.80 HPC timing chart

# ●Package Outline

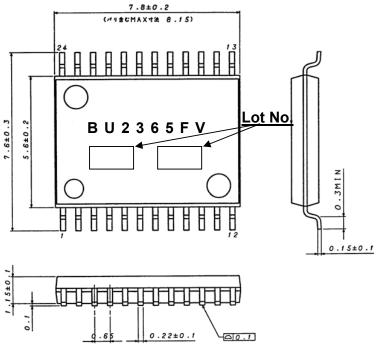
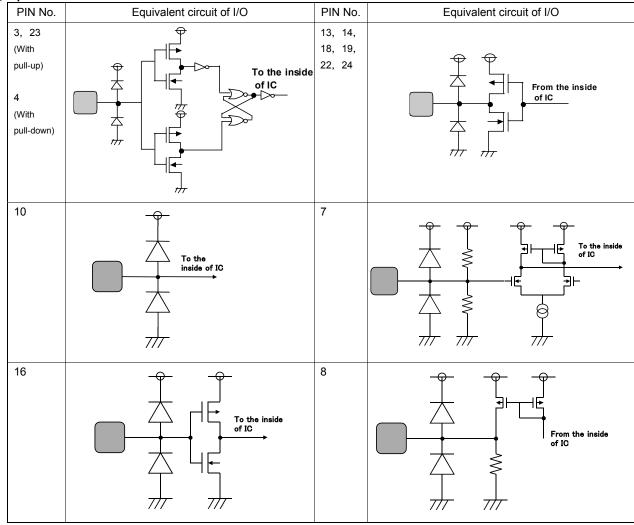


Fig.81 (UNIT:mm)

●Equivalent circuit



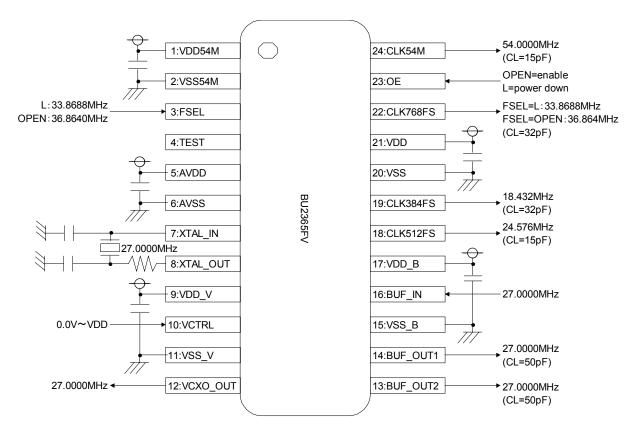


Fig.82

# Notes:

- Mount ICs to the substrate for use. If the ICs are not mounted to the substrate, the characteristics of ICs may not be fully demonstrated.
- 2) Mount 0.1uF capacitors in the vicinity of the IC pins between 1PIN (VDD54M) and 2PIN (VSS54M), 5PIN (AVDD) and 6PIN (AVSS), 9PIN (VDD\_V) and 11PIN (VSS\_V), 17PIN (VDD\_B) and 15PIN (VSS\_B), and 21PIN (VDD) and 20PIN (VSS).
- 3) For the fine-tuning of frequencies, insert several numbers of pF in the 7PIN and 8PIN to GND.
- 4) The electrical characteristics have been all evaluated with the use of the crystal oscillator NX5032GA (Spec. No. EXS00A-00278), manufactured by NIHON DEMPA KOGYO CO., LTD., under the conditions of Limiting resistance Rd=30 Ω and Load CL=10pF. Consequently, in order to use the BU2365FV, the said crystal oscillator is recommended.
- 5) Jitters TYP values vary with the substrate, power supply, output loads, noises, and other. For the use of the BU2365FV, the operating margin should be thoroughly checked.
- 6) Depending on the conditions of the substrate, mount an additional electrolytic capacitor between the power supply and GND terminal
- 7) For EMI protection, it is effective to put ferrite beads in the origin of power supply to be fed to the BU2365FV from the substrate or to insert a capacitor (of  $1\Omega$  or less impedance), which bypasses high frequency desired, between the power supply and the GND terminal.
- 8) Although ROHM is confident that the example application circuit reflects the best possible recommendations, be sure to verify circuit characteristics for your particular application.

#### Cautions on Use

#### 1. Absolute Maximum Ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down devices, thus making impossible to identify breaking mode such as a short circuit or an open circuit. If any special mode exceeding the absolute maximum ratings is assumed, consideration should be given to take physical safety measures including the use of fuses, etc.

#### 2. Recommended operating conditions

These conditions represent a range within which characteristics can be provided approximately as expected. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 3. Reverse connection of power supply connector

The reverse connection of power supply connector can break down ICs. Take protective measures against the breakdown due to the reverse connection, such as mounting an external diode between the power supply and the IC's power supply terminal.

#### 4. Power supply line

Design PCB pattern to provide low impedance for the wiring between the power supply and the GND lines.

In this regard, for the digital block power supply and the analog block power supply, even though these power supplies has the same level of potential, separate the power supply pattern for the digital block from that for the analog block, thus suppressing the diffraction of digital noises to the analog block power supply resulting from impedance common to the wiring patterns. For the GND line, give consideration to design the patterns in a similar manner.

Furthermore, for all power supply terminals to ICs, mount a capacitor between the power supply and the GND terminal. At the same time, in order to use an electrolytic capacitor, thoroughly check to be sure the characteristics of the capacitor to be used present no problem including the occurrence of capacity dropout at a low temperature, thus determining the constant.

#### 5. GND voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient.

#### 6. Short circuit between terminals and erroneous mounting

In order to mount ICs on a set PCB, pay thorough attention to the direction and offset of the ICs. Erroneous mounting can break down the ICs. Furthermore, if a short circuit occurs due to foreign matters entering between terminals or between the terminal and the power supply or the GND terminal, the ICs can break down.

# 7. Operation in strong electromagnetic field

Be noted that using ICs in the strong electromagnetic field can malfunction them.

# 8. Inspection with set PCB

On the inspection with the set PCB, if a capacitor is connected to a low-impedance IC terminal, the IC can suffer stress. Therefore, be sure to discharge from the set PCB by each process. Furthermore, in order to mount or dismount the set PCB to/from the jig for the inspection process, be sure to turn OFF the power supply and then mount the set PCB to the jig. After the completion of the inspection, be sure to turn OFF the power supply and then dismount it from the jig. In addition, for protection against static electricity, establish a ground for the assembly process and pay thorough attention to the transportation and the storage of the set PCB.

#### 9. Input terminals

In terms of the construction of IC, parasitic elements are inevitably formed in relation to potential. The operation of the parasitic element can cause interference with circuit operation, thus resulting in a malfunction and then breakdown of the input terminal. Therefore, pay thorough attention not to handle the input terminals, such as to apply to the input terminals a voltage lower than the GND respectively, so that any parasitic element will operate. Furthermore, do not apply a voltage to the input terminals when no power supply voltage is applied to the IC. In addition, even if the power supply voltage is applied, apply to the input terminals a voltage lower than the power supply voltage or within the guaranteed value of electrical characteristics.

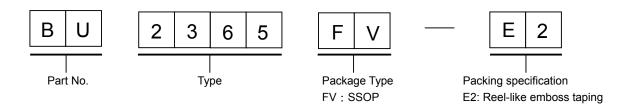
# 10. Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

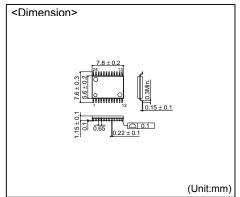
#### 11. External capacitor

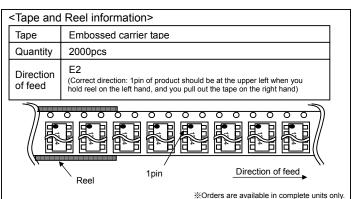
In order to use a ceramic capacitor as the external capacitor, determine the constant with consideration given to a degradation in the nominal capacitance due to DC bias and changes in the capacitance due to temperature, etc.

# Selection of order type



# SSOP-B24





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Appendix1-Rev2.0